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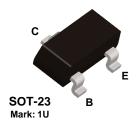
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## **PN2484**

## **MMBT2484**





## **NPN General Purpose Amplifier**

This device is designed for low noise, high gain, general purpose amplifier applications at collector currents from  $1\mu$  to 50 mA. Sourced from Process 07. See 2N5088 for characteristics.

#### **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

| Symbol                            | Parameter  | Value       | Units |  |
|-----------------------------------|--|-------------|-------|--|
| $V_{CEO}$                         | Collector-Emitter Voltage                        | 60          | V     |  |
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | 60          | V     |  |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 5.0         | V     |  |
| Ic                                | Collector Current - Continuous                   | 100         | mA    |  |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |  |

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
   These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### **Thermal Characteristics**

TA = 25°C unless otherwise noted

| Symbol          | Characteristic                          | Max    |           | Units |
|-----------------|---|--------|-----------|-------|
|                 |   | PN2484 | *MMBT2484 |       |
| P <sub>D</sub>  | Total Device Dissipation                | 625    | 350       | mW    |
|                 | Derate above 25°C                       | 5.0    | 2.8       | mW/°C |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case    | 83.3   |           | °C/W  |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 200    | 357       | °C/W  |

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

# NPN General Purpose Amplifier (continued)

| Electri | cai c | zı iai a | <b></b> | JU . |
|---------|-------|----------|---------|------|

TA = 25°C unless otherwise noted

| Symbol            | Parameter                               | Test Conditions   | Min | Max      | Units    |
|-------------------|---|---|-----|----------|----------|
| OFF CHAI          | RACTERISTICS                            |   |     |          |          |
| BV <sub>CBO</sub> | Collector-Base Breakdown Voltage        | $I_C = 10  \mu A,  I_B = 0$   | 60  |          | V        |
| BV <sub>CEO</sub> | Collector-Emitter Breakdown<br>Voltage* | I <sub>C</sub> = 10 mA, I <sub>E</sub> = 0  | 60  |          | V        |
| BV <sub>EBO</sub> | Emitter-Base Breakdown Voltage          | $I_C = 10 \mu A, I_E = 0$   | 6.0 |          | V        |
| I <sub>CBO</sub>  | Collector Cutoff Current                | $V_{CB} = 45 \text{ V}, I_E = 0$<br>$V_{CB} = 45 \text{ V}, I_E = 0, T_A = 150^{\circ}\text{C}$ |     | 10<br>10 | nA<br>μA |
| I <sub>EBO</sub>  | Emitter Cutoff Current                  | $V_{EB} = 5.0 \text{ V}, I_{C} = 0$   |     | 10       | nA       |

#### **ON CHARACTERISTICS**

| h <sub>FE</sub>      | DC Current Gain                      | $\begin{split} I_C &= 1.0 \; \mu\text{A}, \; V_{CE} = 5.0 \; V \\ I_C &= 10 \; \mu\text{A}, \; V_{CE} = 5.0 \; V \\ I_C &= 100 \; \mu\text{A}, \; V_{CE} = 5.0 \; V \\ I_C &= 100 \; \mu\text{A}, \; V_{CE} = 5.0 \; V \\ T_A &= -55^\circ\text{C} \\ I_C &= 500 \; \mu\text{A}, \; V_{CE} = 5.0 \; V \\ I_C &= 1.0 \; \text{mA}, \; V_{CE} = 5.0 \; V \\ I_C &= 10 \; \text{mA}, \; V_{CE} = 5.0 \; V \end{split}$ | 30<br>100<br>175<br>20<br>200<br>250 | 500<br>800 |   |
|----------------------|--------------------------------------|---|--------------------------------------|------------|---|
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | $I_C = 1.0 \text{ mA}, I_B = 0.1 \text{ mA}$  |                                      | 0.35       | V |
| $V_{BE(on)}$         | Base-Emitter On Voltage              | $I_C = 100 \mu\text{A},  V_{CE} = 5.0 \text{V}$   | 0.5                                  | 0.7        | V |

#### SMALL SIGNAL CHARACTERISTICS

| $C_{obo}$        | Output Capacitance | V <sub>CB</sub> =5.0 V, f = 140 kHz  | 6.0 | pF |
|------------------|--------------------|--|-----|----|
| C <sub>ibo</sub> | Input Capacitance  | V <sub>EB</sub> = 0.5 V, f = 140 kHz   | 6.0 | pF |
| NF               | Noise Figure       | $I_C = 10 \mu A$ , $V_{CE} = 5.0 \text{ V}$ , $R_S = 10 \text{k}$ , $f = 1.0 \text{kHz}$ , $BW = 200 \text{ Hz}$ | 3.0 | dB |

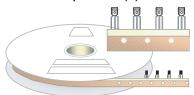
<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu\text{s}$  , Duty Cycle  $\leq$  3.0%

#### **TO-92 Tape and Reel Data** FAIRCHILD SEMICONDUCTOR TM **TO-92 Packaging** Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles CBVK//418019 **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 FSID: PN222N Customized QTY1: QTY2: Label 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code **Pack Options** 2,000 D26Z Е 2,000 D27Z Ammo М 2,000 D74Z D75Z 2,000 **FSCINT** Unit weight = 0.22 gm Reel weight with components = 1.04 kg Ammo weight with components = 1.02 kg Max quantity per intermediate box = 10,000 units Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Immediate Box Customized F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table J18Z TO-18 OPTION STD 2.0 K / BOX Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP 1.5 K / BOX J05Z **FSCINT Label** NO EOL TO-92 STANDARD STRAIGHT FOR: PKG 92, NO LEADCLIP 2.0 K / BOX 94 (NON PROELECTRON SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 L34Z NO LEADCLIP 2.0 K / BOX 2000 units per 114mm x 102mm x 51mm EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

### TO-92 Tape and Reel Data and Package Dimensions, continued

#### **TO-92 Reeling Style** Configuration: Figure 2.0

#### Machine Option "A" (H)

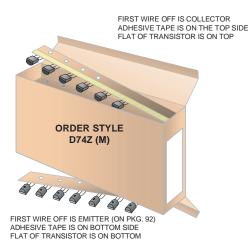


Style "A", D26Z, D70Z (s/h)

# Machine Option "E" (J)

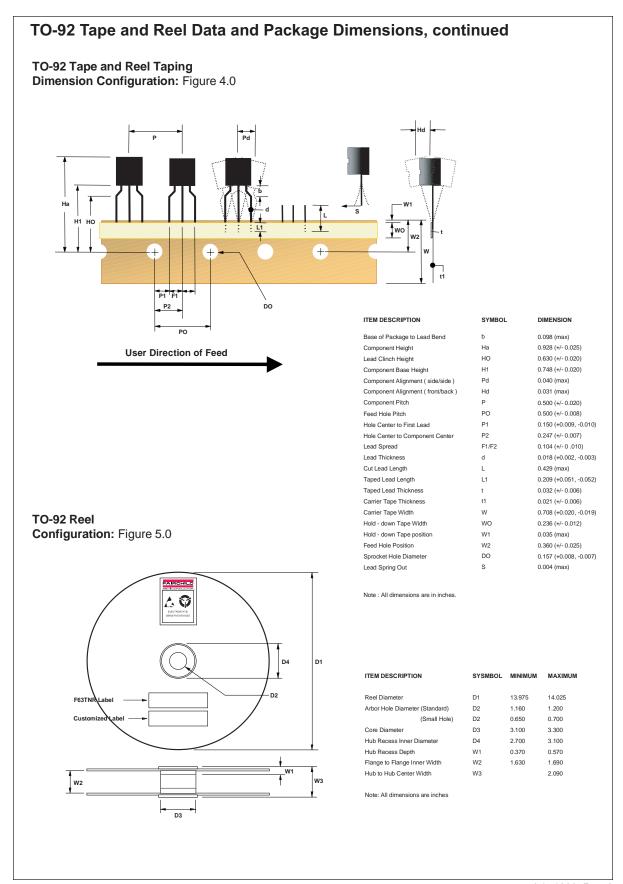
Style "E", D27Z, D71Z (s/h)

#### **TO-92 Radial Ammo Packaging** Configuration: Figure 3.0





FIRST WIRE OFF IS COLLECTOR (ON PKG. 92) ADHESIVE TAPE IS ON BOTTOM SIDE FLAT OF TRANSISTOR IS ON TOP



# **TO-92 Tape and Reel Data and Package Dimensions** TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 96 94 В В 0.76 В G Ε Ø0.060 [Ø1.52] 0.010 [0.254] DEEP В S С 0.615 0.570 5.0°TYP.

January 2000, Rev. B

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|--------------------------|---------------------------|---|
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